Diode Semiconductor Device - Page 1 of 1



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### Inclosure Material:

Glass

# Overall Length:

Between 0.140 inches and 0.195 inches

# Terminal Length:

Between 0.900 inches and 1.300 inches

## **Overall Diameter:**

Between 0.135 inches and 0.185 inches

#### **Function For Which Designed:**

Transient suppressor

#### **Mounting Method:**

Terminal

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

17.10 breakdown voltage, dc

## Voltage Tolerance In Percent:

-5.0/+5.0

#### **Current Rating Per Characteristic:**

59.80 amperes source cutoff current universal and 10.00 microamperes forward current, average outside diameter

## **Power Rating Per Characteristic:**

1500.0 watts small-signal input power, common-collector megahertz

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

#### **Precious Material And Location:**

Terminal surface option silver

#### **Precious Material:**

Silver

#### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/516 government specification

# Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

No

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